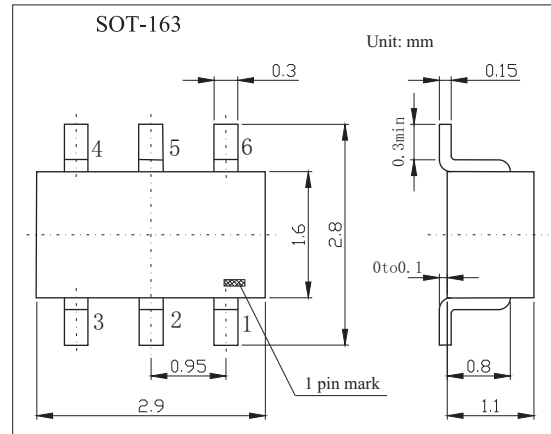
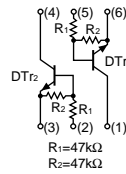


General purpose (dual digital transistors)

IMH2A

■ Features

- Dual NPN digital transistor

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

Parameter	Symbol	Rating	Unit
Supply voltage	V_{CC}	50	V
Input voltage	V_{IN}	40 -10	V
Output current	I_O	30	mA
Collector current	$I_{C(MAX)}$	100	mA
Power dissipation(Total)	P_d	300	mW
Operating and Storage and Temperature Range	T_j, T_{STG}	-55 to +150	$^\circ\text{C}$

■ Electrical Characteristics $T_a = 25^\circ\text{C}$

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Input voltage	$V_{I(off)}$	$V_{CC}=5V, I_O=100\mu A$			0.5	V
	$V_{I(on)}$	$V_O=0.3V, I_O=2mA$	3			V
Output voltage	$V_{O(on)}$	$I_O=10mA, I_I=0.5mA$			0.3	V
Input current	I_I	$V_I=5V$			0.18	mA
Output current	$I_{O(off)}$	$V_{CC}=50V, V_I=0V$			0.5	μA
DC current gain	G_I	$V_O=5V, I_O=5mA$	68			
Transition frequency	f_T	$V_{CE}=10V, I_E=-5mA, f=100MHz$		250		MHz
Input resistance	R_1		32.9	47	61.1	k Ω
Resistance ratio	R_2 / R_1		0.8	1	1.2	

■ Marking

Marking	H2

IMH2A

■ Typical Characteristics

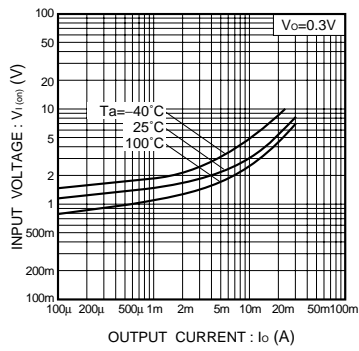


Fig.1 Input voltage vs. output current (on-characteristics)

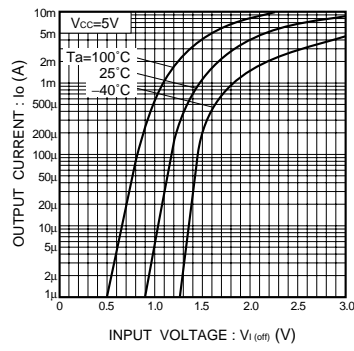


Fig.2 Output current vs. input voltage (off-characteristics)

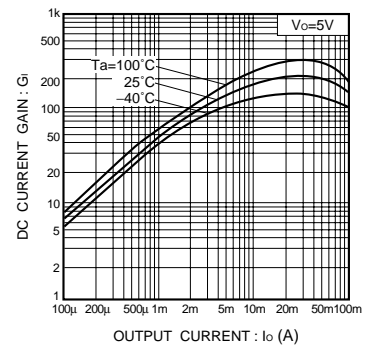


Fig.3 DC current gain vs. output current

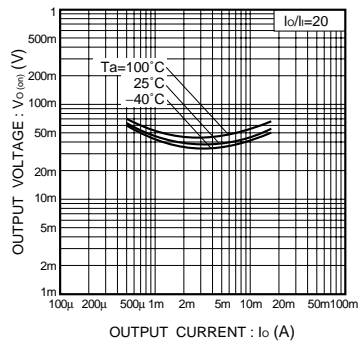


Fig.4 Output voltage vs. output current